

Magnetic relaxation in the "Bragg-glass" phase in BSCCO

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Magnetic relaxation in the Bragg-glass phase of overdoped $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_8$ crystals was investigated using time-resolved magneto-optical visualisation of the flux distribution. This has permitted us to extract the current-voltage characteristic, which can be well described by a power-law, although fits to a stretched exponential $E \sim \exp(-j_c/j)^\mu$ with $0.3 < \mu < 0.8$ are possible at long times in excess of 100 s.

The mixed state in single crystalline $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_8$ (BSCCO) is subdivided in at least two other vortex phases: the high temperature (field) vortex liquid, separated from the low temperature (field) vortex lattice by a first order phase transition (FOT) [1]. Neutron scattering has shown that the low-field phase shows the usual long-range hexagonal vortex lattice order [2]. Nevertheless, the presence of strong pinning at high field and low temperature [3] implies that disorder must play a role even in this phase, which was therefore dubbed "Bragg glass" [4]. The low pinning force density in the Bragg glass, and the possibility to vary the vortex density over several orders of magnitude make this a model system for elastic manifolds in the presence of weak random disorder, and offers the possibility to check the scaling behavior of displacements and displacement correlations. A straightforward means to access this behavior is to measure its transport properties, which depends crucially on the exponents describing the correlations in the random manifold regime [5].

Such measurements at low fields in BSCCO are complicated by at least two factors: (i) they are very sensitive to the presence of intergrowths and other macro-defects, even in very small concentration (ii) the proximity of H_{c1} severely affects the equilibrium vortex distribution and flux flow. The latter circumstance renders the edge barrier against flux penetration very important; in fact,

it dominates the magnetization [6]. In ordinary transport measurements, all the current is carried by the crystal edge, and special measures have to be taken in order to measure the bulk properties of the vortex lattice [7,8]. The latter studies find that in optimally doped BSCCO the activation barrier U opposing vortex creep varies with the current density j as $U \sim j^{-0.5}$ in the range $55 < T < 77$ K [7]; in overdoped BSCCO, Rycroft *et al.* [8] find that $U \propto \ln(j_c/j)$ for $34 < T < 55$ K, reminiscent of two-dimensional vortex dynamics. Still, the high currents required and low electric fields limit the use of traditional transport measurements to $T > 30$ K in BSCCO.

The abovementioned problems can be overcome by the magneto-optical technique. The di-

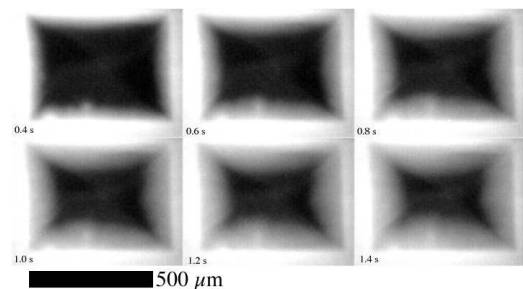


Figure 1. Magneto-optical image of the flux density distribution on the surface of the BSCCO crystal at $T = 18$ K, an applied magnetic field of 440 G, and successive times $0.4 < t < 1.4$ s.

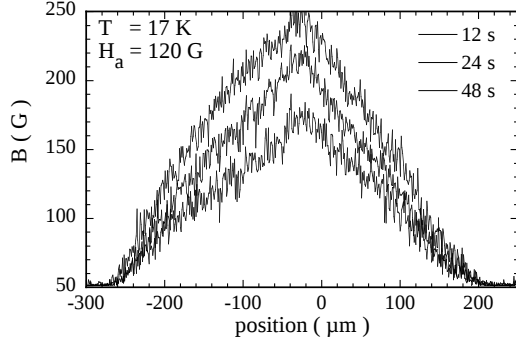


Figure 2. Relaxation of the flux density profile across the surface of the BSCCO sample at $T = 17$ K, after field cooling in 520 G and subsequent rapid decrease of H_a to 120 G.

rect visualisation of the flux density on the sample surface reveals any macrodefects or other inhomogeneities. From the flux density profile, one can easily distinguish between the relative contributions of bulk and surface currents. Using this method, we have measured the temporal relaxation of flux density profiles in an overdoped BSCCO crystal ($T_c = 80$ K; size $477 \times 610 \times 20$ μm), cut and cleaved from a larger crystal grown using the travelling solvent floating zone technique. The Bragg glass phase in our sample extends to $B_{sp} \sim 600$ G at low temperature, much above the first penetration field $H_p \sim 100$ G. In order to minimize the effects of edge barriers we have adopted the following protocol: the field was raised to a value $H_p \ll H_a < B_{sp}$, and then suddenly lowered to the target value. The lowering of the field triggers the acquisition of magneto-optical images at fixed time intervals; such images are displayed in Fig. 1. Intensity profiles taken across the crystal width are converted to flux density profiles (Fig. 2) using a calibration measurement above T_c . The near-perfect linearity of these profiles, in correspondence with single-vortex pinning and the Bean model, inspired us to take the slope $\partial B / \partial x$ as being representative of the bulk screening current j . Current density vs. time is plotted in Fig. 3.

The result, depicted in Fig. 3(a), shows that j follows a near-perfect power-law behavior, $j \propto t^{-0.50}$, for all $14 < T < 23$ K. This corresponds

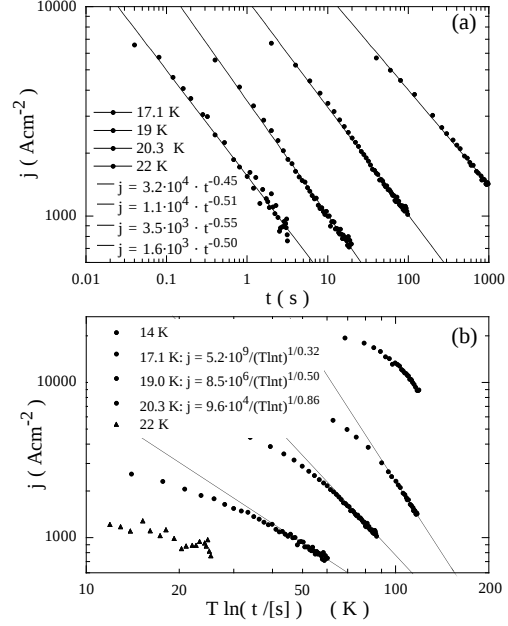


Figure 3. (a) Bulk current density vs. time (b) vs. $T \cdot \ln(t)$, for different temperatures.

to an $I(V)$ -law: $E \propto j^3$, as found in Ref. [8] near the FOT. However, solving Maxwell's equations show that such a shallow $I(V)$ -law cannot result in the sharp linear profiles of Fig. 2 [9]. It is therefore better to parameterize the curves along the collective creep prediction: $j \propto [T \ln(t/\tau)]^{1/\mu}$ [5]. Fig. 3(b) shows that at long times this relation is obeyed with a temperature dependent exponent $0.36 < \mu < 0.86$, as in Ref. [7], and close to the theoretical result of $0.5 < \mu < 0.8$ [4].

REFERENCES

1. E. Zeldovet *et al.*, Nature **375**, 373 (1995).
2. R. Cubitt *et al.*, Nature **365**, 410 (1993).
3. M. Konczykowski *et al.*, this conference.
4. T. Giamarchi and P. Le Doussal, Phys. Rev. B Lett. **52**, 1242 (1995).
5. M.V. Feigel'man *et al.*, Phys. Rev. Lett. **63**, (1989).
6. N. Chikumoto *et al.*, Phys. Rev. Lett. **69**, 1260 (1992).
7. D. Fuchs *et al.*, Phys. Rev. Lett. **81**, 3944 (1998).
8. S. Rycroft *et al.*, Phys. Rev. B **60**, R757 (1999).
9. J. Gilchrist and C.J. van der Beek, Physica C **231**, 147 (1994).